

GLF73510 Nano-Current Consumed, IoSmart™ Battery Protection Switch

Product Specification

DESCRIPTION

The GLF73510 is an I_QSmart^{TM} ultra-efficiency, 2 A rated switch with the accurate turn-off threshold to prevent a battery from being discharged deeply.

When the voltage of a battery decreases to the off threshold voltage level, the GLF73510 is turned off, consuming an ultra-low leakage current (I_{SD}) to save the battery. The GLF73510 remains in the off state until a higher voltage is applied to V_{OUT} pin. Note that the GLF73510 is enabled only by V_{OUT} voltage with a charger output.

With the higher V_{OUT} voltage from a charger applied, the GLF73510 is fully turned on and monitors V_{BAT} voltage. When the V_{OUT} voltage of a charger is less than the on threshold voltage, a battery can be charged through the body diode of the main switch.

In case that a charged battery is assembled without a higher V_{OUT} applied, the GLF73510 continues to stay at the sleep mode, consuming an ultra-low leakage current (I_{SD}) to save the battery, during shipping or storage.

The GLF73510 is available in 0.97 mm x 0.97 mm x 0.55 mm wafer level chip scale package (WLCSP).

FEATURES

Off Threshold Voltage to Protect Battery
 Discharge

 V_{TH_OFF} : V_{BAT} =3.05 V

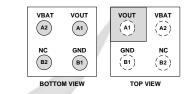
Contact GLF for a different VTH level

- Switch is activated only by the V_{OUT} voltage of a charger output
- Ultra-Low Iq: 500 nA Typ @ VBAT=3.6 V
 - Ultra-Low I_{SD}: 2 nA Typ @ V_{BAT} =1.1 V 6 nA Typ @ V_{BAT} =3.6 V
- Low R_{ON}: 30 mΩ Typ @ V_{BAT}=3.6 V
 28 mΩ Typ @ V_{BAT}=4.2 V
- IOUT Max : 2 A
- Temperature Range: -40 to 85 °C
- HBM: 6kV, CDM: 2 kV
- Ultra-Small : 0.97 mm x 0.97 mm WLCSP

APPLICATIONS

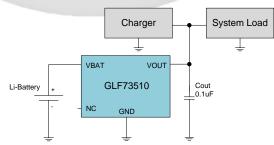
- Battery protection
- Wearables / IoT Devices
- Mobile Devices
- Mobile Medical

PACKAGE



0.97 mm x 0.9 7mm x 0.55 mm WLCSP

APPLICATION DIAGRAM



Note: 1) The GLF73510 can be activated by applying a voltage above V_{ON} to the V_{OUT} pin.

2) When the GLF73510 is at the off state, the battery can be charged through the body diode of the main switch.

DEVICE INFORMATION

| Part Number | Top Mark | Ron Threshol (Typ) VBAT=3.6V VTH_OFF | | | | | |
|-------------|----------|---|--------|--|--|--|--|
| GLF73510 | UA | 30 mΩ | 3.05 V | | | | |

FUNCTIONAL BLOCK DIAGRAM

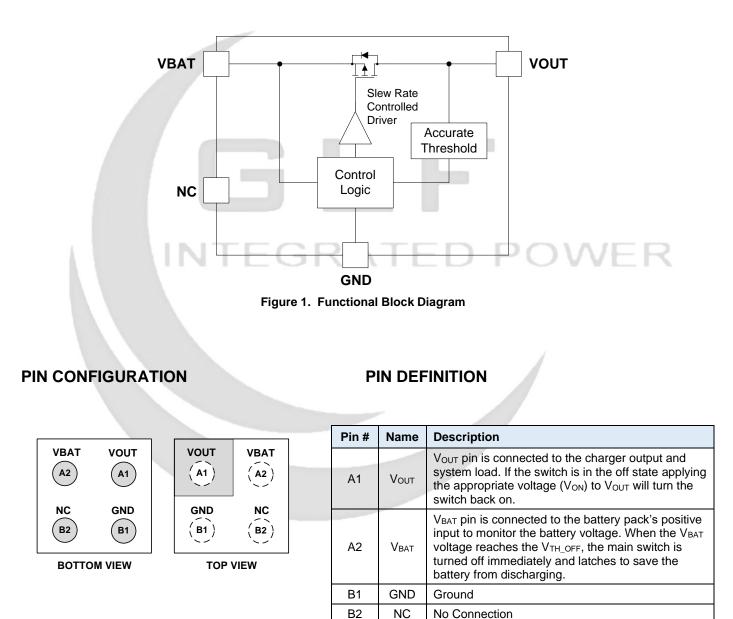


Figure 2. 0.97 mm x 0.97 mm x 0.55 mm WLCSP

GLF INTEGRATED POWER Nano-Current Consumed, IQSmart[™] Battery Protection Switch

ABSOLUTE MAXIMUM RATINGS

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions; extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Par | Min. | Max. | Unit | | |
|------------------|--|-----------------------------------|------|------|----|--|
| Vbat, Vout | Each Pin Voltage to GND | Each Pin Voltage to GND | | | | |
| I _{OUT} | Maximum Continuous Switch Current | Maximum Continuous Switch Current | | | | |
| PD | Power Dissipation at T _A = 25°C | | 1.2 | W | | |
| Tstg | Storage Junction Temperature | -65 | 150 | °C | | |
| TA | Operating Temperature Range | -40 | 85 | °C | | |
| θја | Thermal Resistance, Junction to Ambie | | 85 | °C/W | | |
| ESD | Electrostatic Discharge Capability | Human Body Model, JESD22-A114 | 6 | | kV | |
| ESD | Electrostatic Discharge Capability | Charged Device Model, JESD22-C101 | 2 | | κv | |

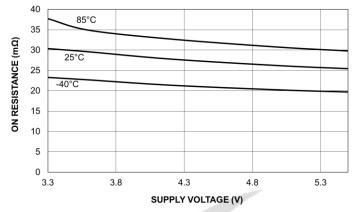
ELECTRICAL CHRACTERISTICS

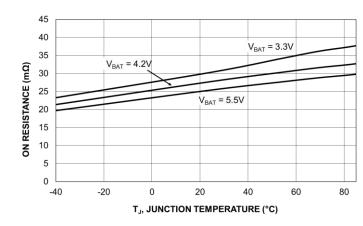
Values are at $T_A = 25$ °C unless otherwise noted.

| Symbol | Parameter | Condition | S | Min. | Тур. | Max. | Unit |
|------------|---|---|-----------------------------------|------|------|------|------|
| Vbat, Vout | Operating Voltage | | | 1.1 | | 5.5 | V |
| V | OFF Threshold Voltage | VBAT decreases until switch turns OFF | | | 3.05 | 3.20 | v |
| Vth_off | OFF Theshold Vollage | V _{BAT} decreases until switch tur | | 2.9 | | V | |
| Von | ON Voltage applied to | Vout increases until switch turr | IS ON, VBAT =3.6 V ⁽²⁾ | | 3.5 | | v |
| VON | Vout | V_{OUT} increasing, V_{BAT} =3.6 V, | \sum | 3.4 | | V | |
| | | VBAT = 3.6 V, IOUT=0 mA, Switc | n = ON | | 0.51 | | |
| lq | Quiescent Current with | VBAT = 4.2 V, IOUT=0 mA, Switc | | | 0.73 | 1 | uA |
| iQ | Switch On | V_{BAT} = 4.2 V, I _{OUT} =0 mA, Switc | | | 0.70 | | |
| | | V_{BAT} = 4.2 V, I_{\text{OUT}}=0 mA, Switch = ON, Ta=85 °C $^{(1)}$ | | | 0.69 | | |
| | | VBAT = 1.1 V, VOUT = 0 V | | 1 | 2 | | |
| | | V _{BAT} = 2.5 V, V _{OUT} = 0 V | | | 3 | | nA |
| | Shutdown Current | V _{BAT} = 3.3 V, V _{OUT} = 0 V | | | 5 | | |
| Isd | | V _{BAT} = 3.6 V, V _{OUT} = 0 V | | | 6 | | |
| | | $V_{BAT} = 4.2 \text{ V}, V_{OUT} = 0 \text{ V}$ | | | 9 | 50 | |
| | | V _{BAT} = 4.2 V, V _{OUT} = 0 V, Ta=5 | | 0.06 | | uA | |
| | | $V_{BAT} = 4.2 V, V_{OUT} = 0 V, Ta=8$ | 5 °C ⁽¹⁾ | | 0.55 | | 0/1 |
| | | | Ta=25 °C | | 28 | 32 | |
| | On-Resistance | VBAT=4.2 V, IOUT= 500 mA | Ta=55 °C (1) | | 30 | | mΩ |
| | | | Ta=85 °C (1) | | 33 | | |
| Ron | | | Ta=25 °C | | 30 | 34 | |
| | | V _{BAT} =3.6 V, I _{OUT} = 500 mA | Ta=55 °C ⁽¹⁾ | | 32 | | |
| | | | Ta=85 °C ⁽¹⁾ | | 35 | | |
| | | V _{BAT} =3.3 V, I _{OUT} = 500 mA | Ta=25 °C | | 31 | 35 | 1 |
| VF | Forward Voltage of Diode ⁽¹⁾ | IF= 5 mA | | | 0.4 | | V |
| toff | Turn-Off Time (1) | Cout=0.1 μF, Rout=150 Ω, Vou | IT = VTH_OFF to 0 V | | 36 | | us |

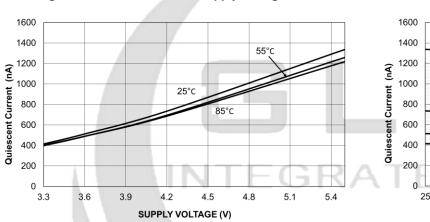
Notes: 1. By design; characterized, not production tested. 2. See Figure 10 for details.

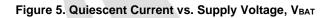
TYPICAL PERFORMANCE CHARACTERISTICS

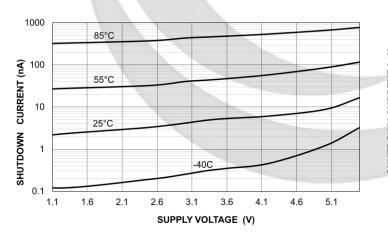












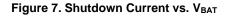


Figure 4. On-Resistance vs. Temperature

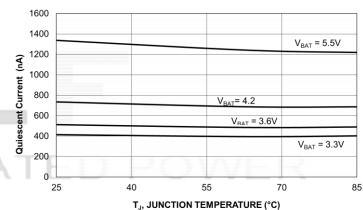


Figure 6. Quiescent Current vs. Temperature

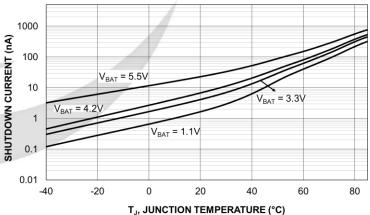
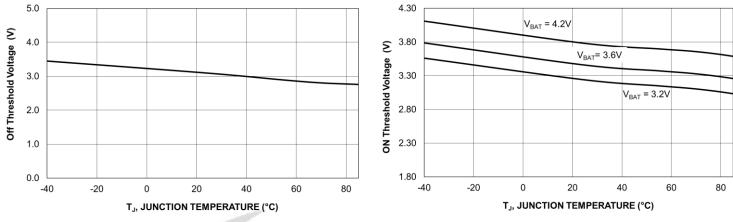
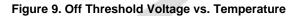


Figure 8. Shutdown Current vs. Temperature









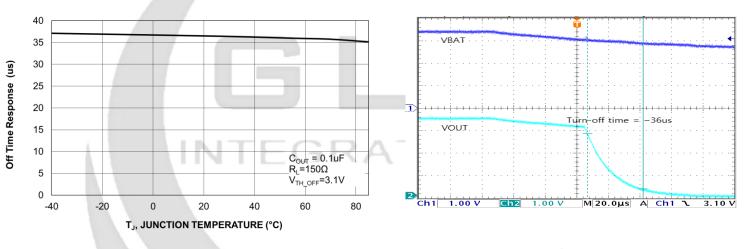
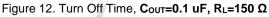


Figure 11. Off Time Response



GLF INTEGRATED POWER Nano-Current Consumed, IoSmart[™] Battery Protection Switch

APPLICATION INFORMATION

The GLF73510 is an ultra-efficiency, 2 A rated, load switch with accurate ON/OFF threshold voltage and integrated slew rate control. The best in class efficiency makes it an ideal chose for use in wearables, IoT devices, and mobile electronics.

ON / OFF Threshold

When the voltage of a battery decreases to the off threshold voltage level, the GLF73510 is turned off, consuming an ultra-low leakage current to save the battery. The GLF73510 remains in the off state until a higher voltage is applied to the V_{OUT} pin. Note that the GLF73510 is enabled only by the V_{OUT} pin with a higher voltage than the on threshold voltage. With the higher V_{OUT} voltage from a charger applied, the GLF73510 is fully turned on and monitors the V_{BAT} voltage. When the V_{OUT} voltage of a charger is less than the on threshold voltage, a battery can be charged through the body diode of the main switch.

Output Capacitor

An output capacitor is not required for GLF73510 operation. However, a 0.1 uF capacitor is recommended to be placed close to the V_{OUT} pin to mitigate an undershoot voltage or the transient voltage peak caused by a hot-plugging voltage source.

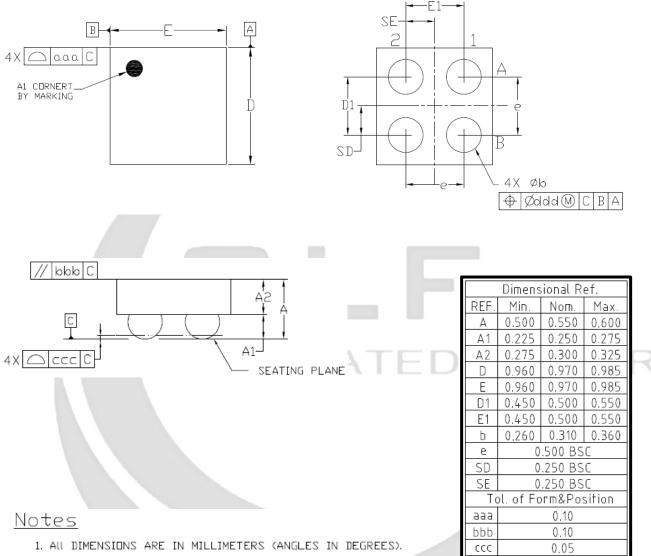
Board Layout

All traces should be as short as possible to minimize parasitic inductance effects. Wide traces for V_{BAT}, V_{OUT}, and GND will help reduce voltage drops, and parasitic effects during dynamic operation as well as improve the thermal performance at high load currents.

IEGRATED POW

GLF INTEGRATED POWER Nano-Current Consumed, IQSmart[™] Battery Protection Switch

PACKAGE OUTLINE



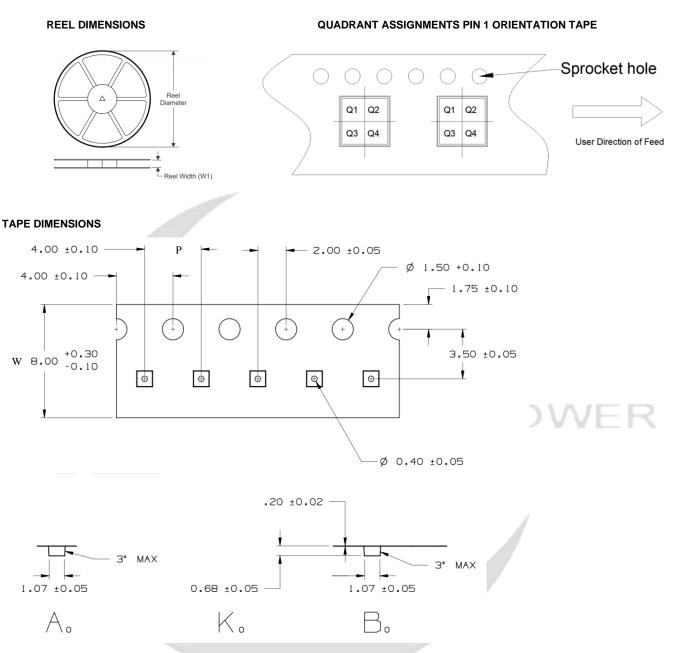
2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.

ddd

0.05

GLF73510 INTEGRATED POWER Nano-Current Consumed, IoSmart[™] Battery Protection Switch

TAPE AND REEL INFORMATION



| Device | Package | Pins | SPQ | Reel Diameter(mm) | Reel Width W1 | A0 | В0 | KO | Ρ | w | Pin1 |
|----------|---------|------|------|-------------------|------------------|------|------|------|---|---|------|
| GLF73510 | WLCSP | 4 | 3000 | 180 | 9 | 1.07 | 1.07 | 0.68 | 4 | 8 | Q1 |

Remark:

- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- C0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P: Pitch between successive cavity centers

GLF73510

INTEGRATED POWER Nano-Current Consumed, IoSmartTM Battery Protection Switch

SPECIFICATION DEFINITIONS

| Document Type | Meaning | Product Status |
|------------------------------|---|----------------|
| Target Specification | pecification limits. GLF reserves the right to change limits at any time without warning or notification. A target specification in no way guarantees future production of the device in question. Preliminary This is a draft version of a product specification. The specification is still under internal review and subject to change. GLF reserves the right to change the specification at any time without warning or potification. | |
| Preliminary Specification | | |
| Product Specification | This document represents the anticipated production performance characteristics of the device. | Production |

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